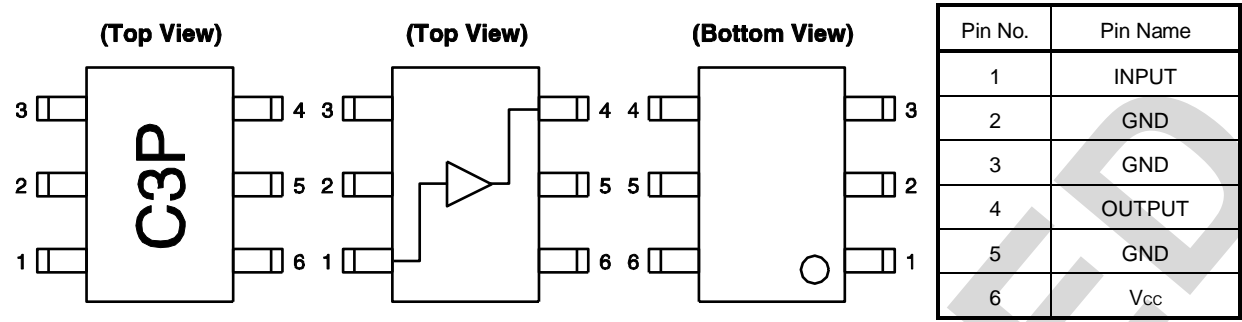


PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Conditions | Ratings | Unit |
|-------------------------------|------------------|------------------------------------|-------------|------|
| Supply Voltage | V _{CC} | T _A = +25°C | 6.0 | V |
| Total Circuit Current | I _{CC} | T _A = +25°C | 15 | mA |
| Power Dissipation | P _D | T _A = +85°C Note | 270 | mW |
| Operating Ambient Temperature | T _A | | −40 to +85 | °C |
| Storage Temperature | T _{stg} | | −55 to +150 | °C |
| Input Power | P _{in} | T _A = +25°C | +10 | dBm |

Note Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

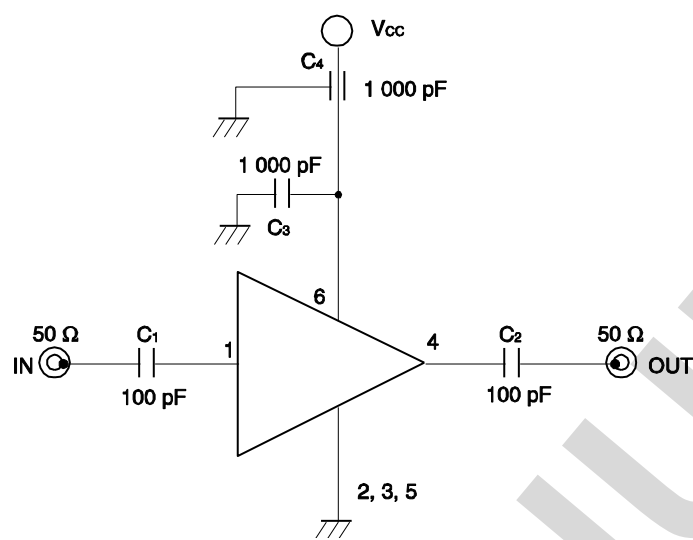
RECOMMENDED OPERATING RANGE

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------|-----------------|------------|------|------|------|------|
| Supply Voltage | V _{CC} | | 4.5 | 5.0 | 5.5 | V |
| Operating Ambient Temperature | T _A | | −40 | +25 | +85 | °C |

ELECTRICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, $V_{CC} = 5.0\text{ V}$, $Z_S = Z_L = 50\ \Omega$)

| Parameter | Symbol | Test Conditions | MIN. | TYP. | MAX. | Unit |
|---|-------------------|---|-------|-------|------|------|
| Circuit Current | I_{CC} | No input signal | 4.0 | 4.8 | 6.0 | mA |
| Power Gain 1 | G_{P1} | $f = 0.1\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 20.5 | 22.5 | 24.5 | dB |
| Power Gain 2 | G_{P2} | $f = 1.0\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 19.5 | 22.0 | 24.5 | |
| Power Gain 3 | G_{P3} | $f = 1.8\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 19.0 | 22.0 | 25.0 | |
| Power Gain 4 | G_{P4} | $f = 2.2\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 19.0 | 22.0 | 25.0 | |
| Power Gain 5 | G_{P5} | $f = 2.6\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 19.0 | 22.0 | 25.0 | |
| Power Gain 6 | G_{P6} | $f = 3.0\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 18.0 | 21.0 | 24.5 | |
| Saturated Output Power 1 | $P_{O(sat)1}$ | $f = 1.0\text{ GHz}$, $P_{in} = -12\text{ dBm}$ | -3.5 | -1.0 | - | dBm |
| Saturated Output Power 2 | $P_{O(sat)2}$ | $f = 2.2\text{ GHz}$, $P_{in} = -12\text{ dBm}$ | -6.0 | -3.5 | - | |
| Gain 1 dB Compression Output Power 1 | $P_{O(1dB)1}$ | $f = 1.0\text{ GHz}$ | -9.0 | -6.5 | - | dBm |
| Gain 1 dB Compression Output Power 2 | $P_{O(1dB)2}$ | $f = 2.2\text{ GHz}$ | -11.0 | -8.0 | - | |
| Noise Figure 1 | NF1 | $f = 1.0\text{ GHz}$ | - | 4.7 | 5.5 | dB |
| Noise Figure 2 | NF2 | $f = 2.2\text{ GHz}$ | - | 4.6 | 5.5 | |
| Isolation 1 | ISL1 | $f = 1.0\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 35 | 40 | - | dB |
| Isolation 2 | ISL2 | $f = 2.2\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 35 | 43 | - | |
| Input Return Loss 1 | RL_{in1} | $f = 1.0\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 7.5 | 10.5 | - | dB |
| Input Return Loss 2 | RL_{in2} | $f = 2.2\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 7.5 | 10.5 | - | |
| Output Return Loss 1 | RL_{out1} | $f = 1.0\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 10.0 | 13.5 | - | dB |
| Output Return Loss 2 | RL_{out2} | $f = 2.2\text{ GHz}$, $P_{in} = -40\text{ dBm}$ | 7.5 | 9.5 | - | |
| Input 3rd Order Distortion Intercept Point 1 | IIP ₃₁ | $f_1 = 1\ 000\text{ MHz}$, $f_2 = 1\ 001\text{ MHz}$, $P_{in} = -40\text{ dBm}$ | - | -18.0 | - | dBm |
| Input 3rd Order Distortion Intercept Point 2 | IIP ₃₂ | $f_1 = 2\ 200\text{ MHz}$, $f_2 = 2\ 201\text{ MHz}$, $P_{in} = -40\text{ dBm}$ | - | -20.5 | - | |
| Output 3rd Order Distortion Intercept Point 1 | OIP ₃₁ | $f_1 = 1\ 000\text{ MHz}$, $f_2 = 1\ 001\text{ MHz}$, $P_{in} = -40\text{ dBm}$ | - | +4.0 | - | dBm |
| Output 3rd Order Distortion Intercept Point 2 | OIP ₃₂ | $f_1 = 2\ 200\text{ MHz}$, $f_2 = 2\ 201\text{ MHz}$, $P_{in} = -40\text{ dBm}$ | - | +1.5 | - | |
| 2nd Order Intermodulation Distortion | IM ₂ | $f_1 = 1\ 000\text{ MHz}$, $f_2 = 1\ 001\text{ MHz}$, $P_{in} = -40\text{ dBm}$ | - | 30.5 | - | dBc |
| K factor 1 | K1 | $f = 1.0\text{ GHz}$ | - | 3.8 | - | - |
| K factor 2 | K2 | $f = 2.2\text{ GHz}$ | - | 3.9 | - | - |

TEST CIRCUIT



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

COMPONENTS OF TEST CIRCUIT FOR MEASURING ELECTRICAL CHARACTERISTICS

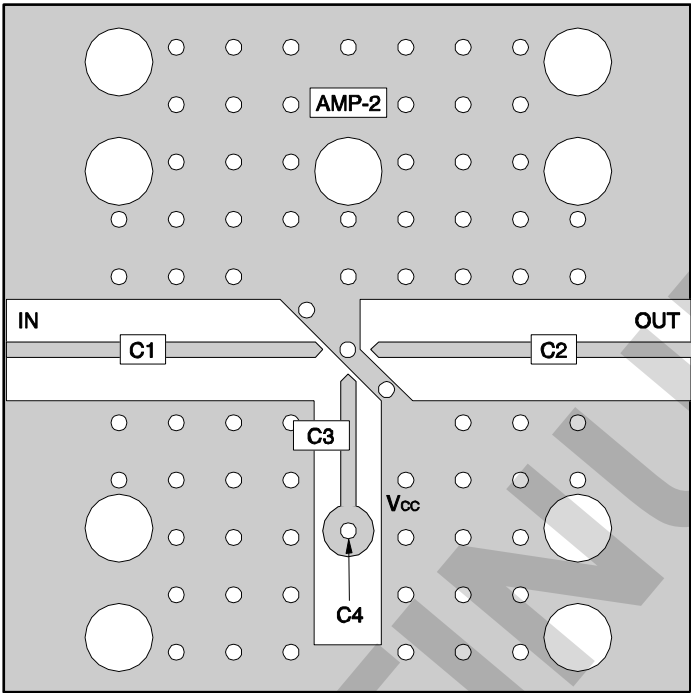
| | Type | Value |
|--------|------------------------|----------|
| C1, C2 | Chip Capacitor | 100 pF |
| C3 | Chip Capacitor | 1 000 pF |
| C4 | Feed-through Capacitor | 1 000 pF |

CAPACITORS FOR Vcc AND INPUT PINS

Bypass capacitor for Vcc pin is intended to minimize Vcc pin's ground impedance. Therefore, stable bias can be supplied against Vcc fluctuation.

Coupling capacitors for input/output pins are intended to minimize RF serial impedance and cut DC.

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

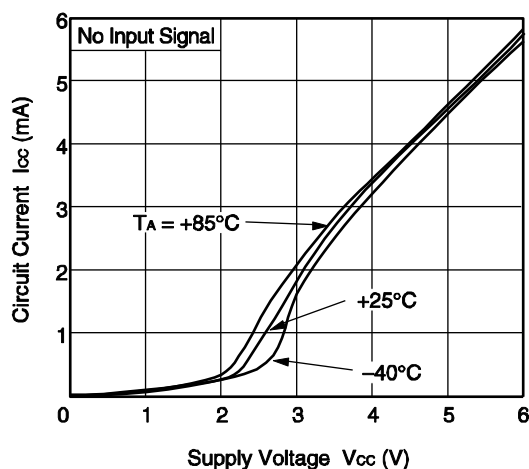
| | Value |
|--------|----------|
| C1, C2 | 100 pF |
| C3, C4 | 1 000 pF |

Notes

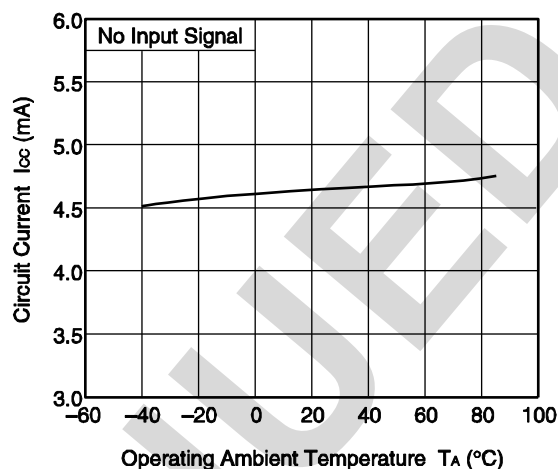
1. 30 × 30 × 0.4 mm double sided copper clad polyimide board.
2. Back side: GND pattern
3. Solder plated on pattern
4. ◦○: Through holes

TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, $V_{CC} = 5.0\text{ V}$, $Z_S = Z_L = 50\ \Omega$, unless otherwise specified)

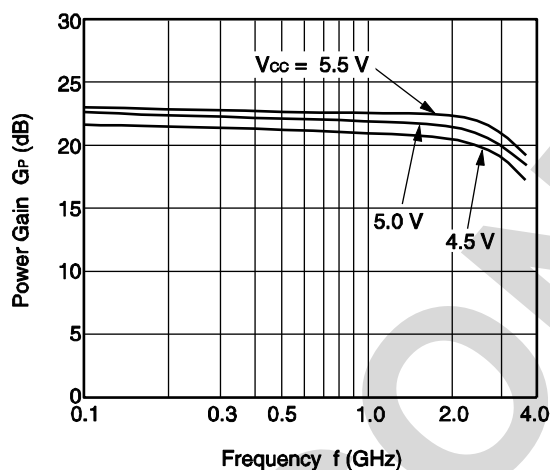
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



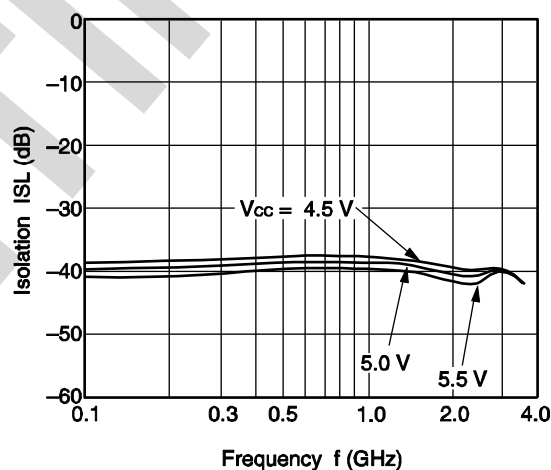
CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE



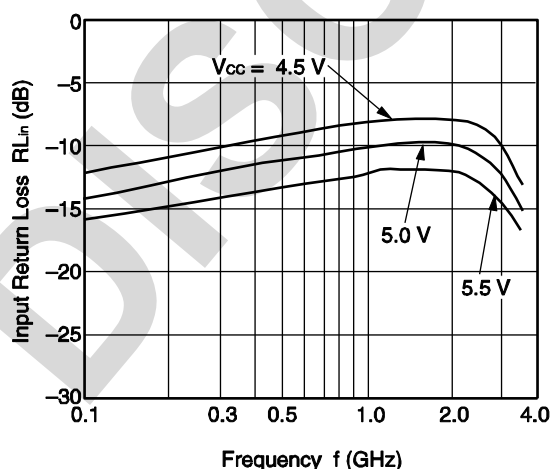
POWER GAIN vs. FREQUENCY



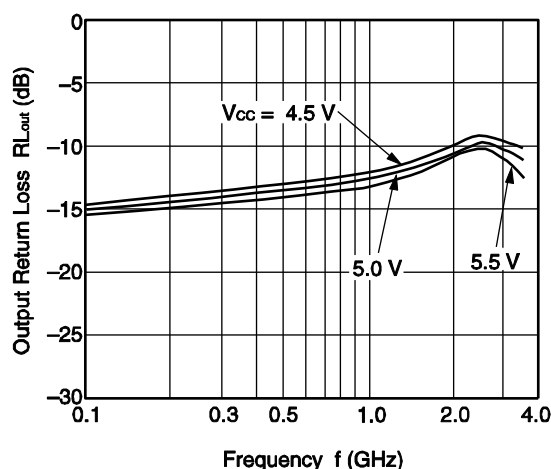
ISOLATION vs. FREQUENCY



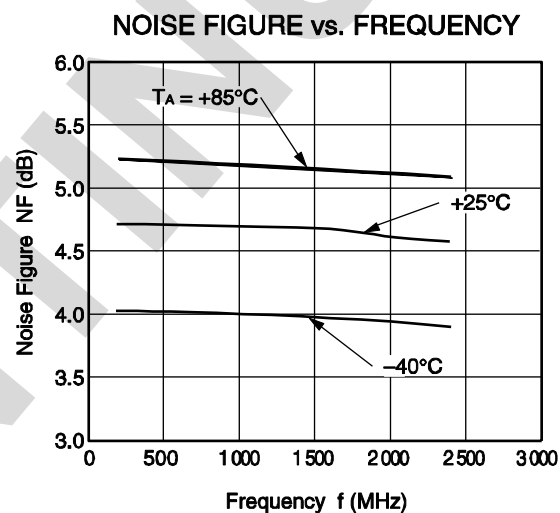
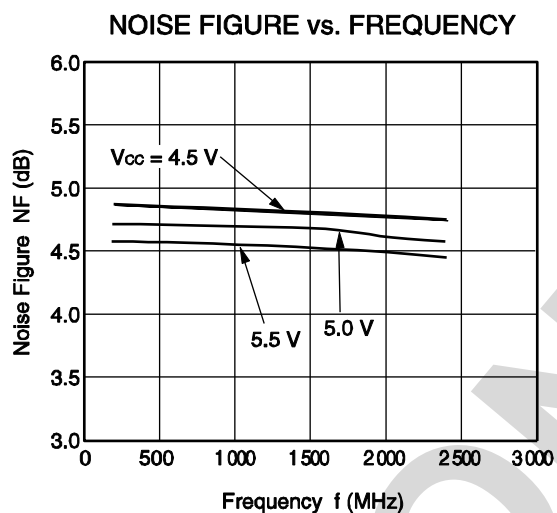
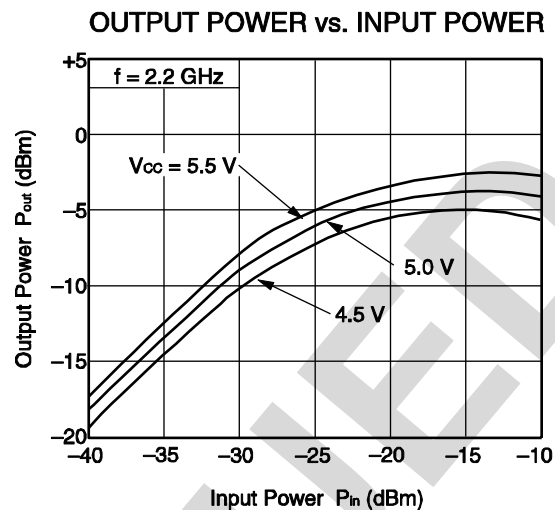
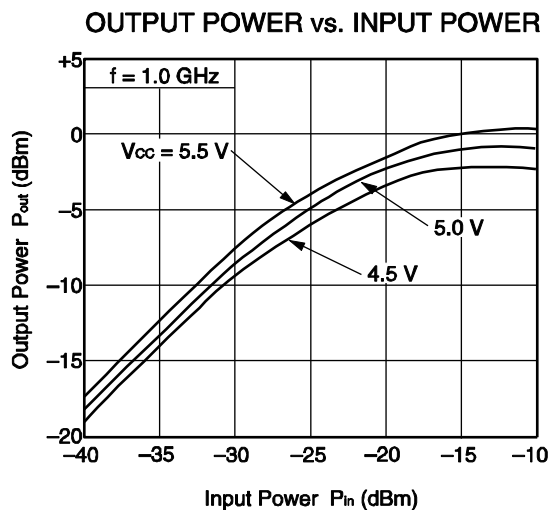
INPUT RETURN LOSS vs. FREQUENCY



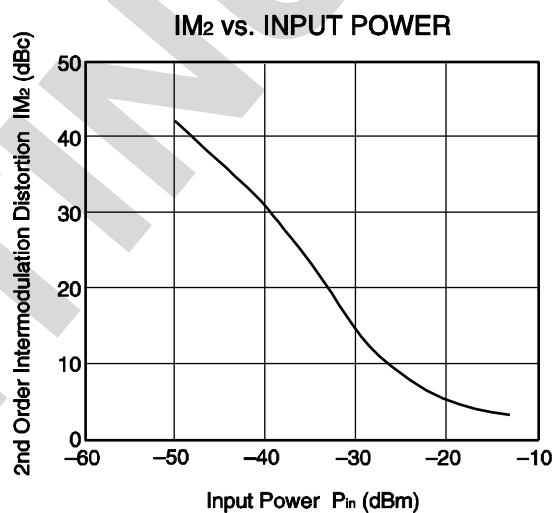
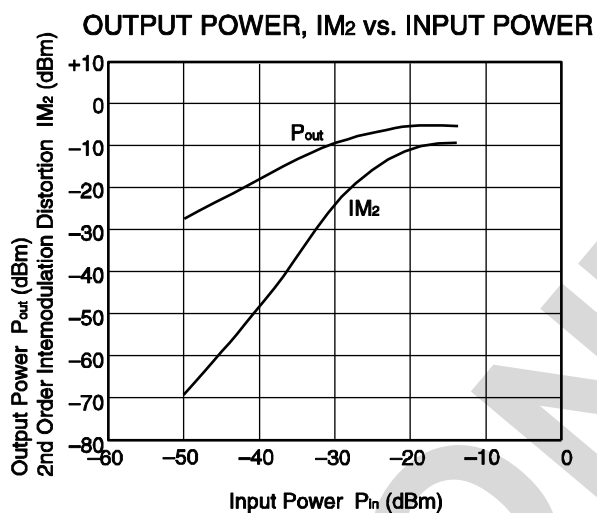
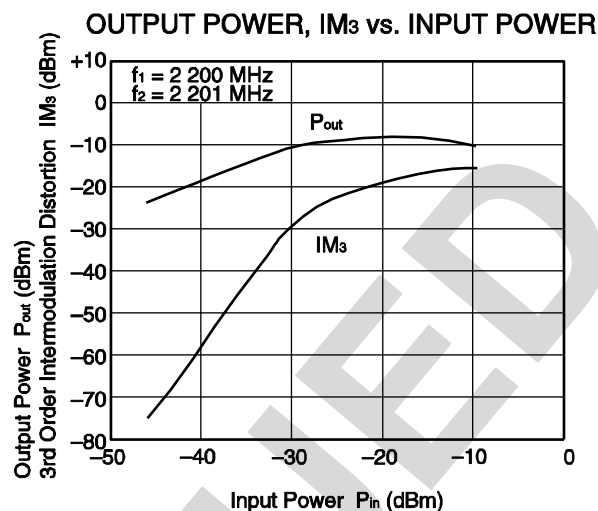
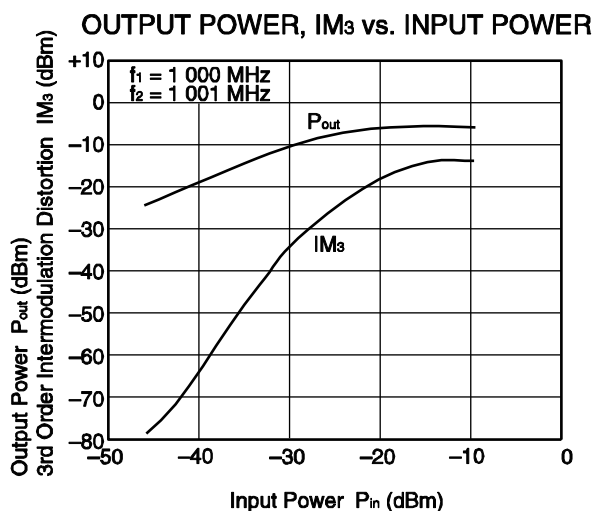
OUTPUT RETURN LOSS vs. FREQUENCY



Remark The graphs indicate nominal characteristics.



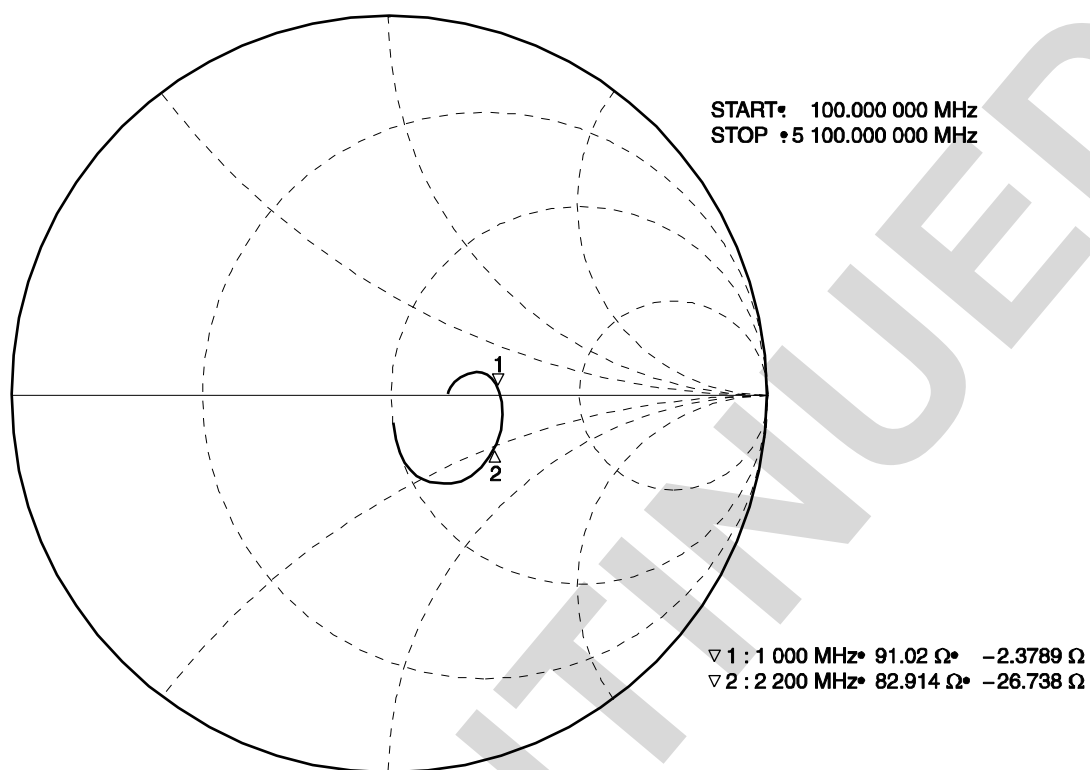
Remark The graphs indicate nominal characteristics.



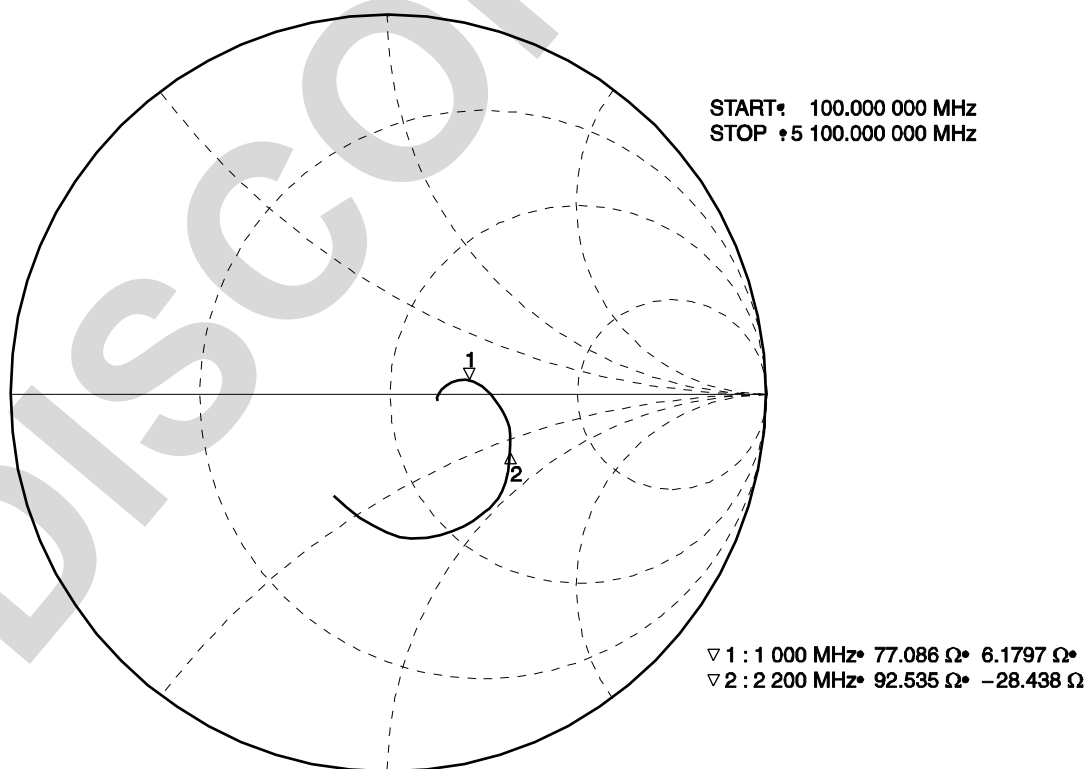
Remark The graphs indicate nominal characteristics.

S-PARAMETERS ($T_A = +25^\circ\text{C}$, $V_{CC} = 5.0\text{ V}$, $P_{in} = -40\text{ dBm}$)

S₁₁—FREQUENCY

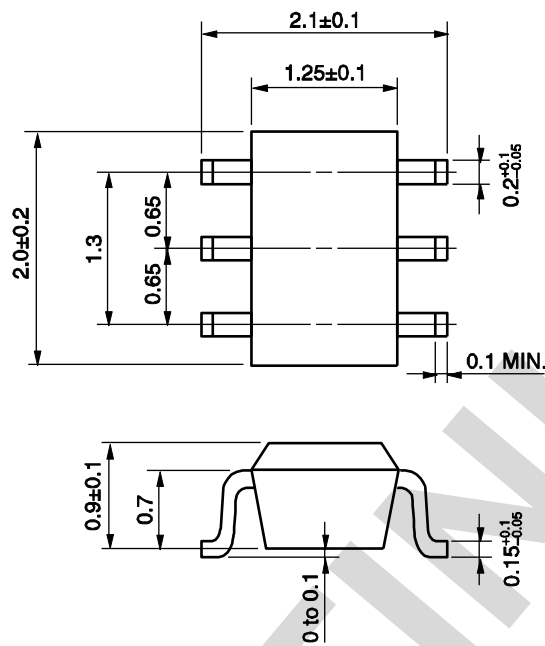


S₂₂—FREQUENCY



PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
All the ground terminals must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to the V_{cc} line.
- (4) The DC cut capacitor must be attached to input and output pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

| Soldering Method | Soldering Conditions | Condition Symbol |
|------------------|---|------------------|
| Infrared Reflow | Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | IR260 |
| Wave Soldering | Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | WS260 |
| Partial Heating | Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | HS350 |

Caution Do not use different soldering methods together (except for partial heating).